

An Overview of High Temperature Technologies for Venus Surface Applications

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Outline

- Introduction
- Venus Technology Plan
- Venus Surface Platform Study
- Long Lived Platform Development
	- **≻**Electronics
	- **≻ Sensors**
	- \triangleright Communication
	- Power
	- Summary and Future Prospects

Introduction

- Venus has a very hostile environment with an average surface temperature of 465°C and surface atmospheric pressure of 90 atm. in the presence of corrosive species
- Missions that have landed on the surface of Venus have typically lasted at most \sim 2 hours due to the high temperatures and harsh conditions
- Long term measurement of Venus planetary conditions has been limited by the lack of electronics, communications, power, sensors, instrument, and actuation systems operational in the harsh Venus environment
- Surface exploration of Venus for extended durations has notable science impact and is becoming more viable
- This presentation will provide a sampling of high temperature development and technologies that may have an impact on future Venus surface exploration

Technology Development Overview

- Technologies relevant for Venus surface applications may often have their origin in other harsh environment applications e.g., aeronautics or industrial processing
- Material systems and engineering approaches standardly used for even harsh environment terrestrial applications may not be viable for Venus missions
- A major challenge is operation in Venus surface conditions without significant degradation and for extended periods of time
- Testing of proposed technologies in first at high temperature leading up to Venus simulated conditions include relevant chemistry, is core to technology advancement
- The status of Venus technology development is in some cases at the level of 1970's to 1980's technology; at these levels significant science can be accomplished.
- A mission needs a complete compliment of relevant technologies for success

Material Choice (and GEER Testing) Matters

SiC Clock IC Chip Optical Microscope Photos (These IC Materials Work - Chip operated for 60 days)

Wave Guide Before and After 60 Days of GEER Testing (These materials react – grow crystals – will NOT work)

Evolving "Handbook" of What Works in Venus Ambients

https://agupubs.onlinelibrary.wiley.com/doi/full/10.1029/2017EA000355

VEXAG Venus Technology Plan 2019

VEXAG Technology Plan 2019 Generic Mission Descriptions

VEXAG Technology Plan 2019 Near-Term 2018 to 2022 : We Can Do A Lot Now

Key

VEXAG Technology Plan 2019 Evalutation Criteria

VEXAG Technology Plan 2019 Mid-Term 2023 to 2032: From This Baseline, New Missions and Science in Next Decadal Period

VEXAG Technology Plan 2019

Far-Term 2033 to 2042 : Venus Exploration More Like

Other Planets, but Major Challenges

Venus Surface Platform Study On-Going Leads: T. Kremic and M. Amato

Venus Surface Platform Study Lander Characteristics

Venus Surface Platform Study Capability to Science Links

An "H" in a field signifies that the capability is highly impactful in understanding that aspect of the science. A "S" in a field signifies somewhat impactful.

Technology To Capability Links

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Long Lived Surface Platforms Development LLISSE, SAEVe, HOTTech, etc.

LONG-LIVED IN-SITU SOLAR SYSTEM EXPLORER (LLISSE) PI TIBOR KREMIC, NASA GLENN

LONG-LIVED IN-SITU SOLAR SYSTEM EXPLORER (LLISSE)

- LLISSE is a small and "independent" probe for Venus surface applications
- LLISSE acquires and transmits simple but important science
- Three key elements leveraged
	- Recent developments in high temperature electronics
	- Focused, low data volume measurements
	- Novel operations scheme
- Operations Goals:
	- Operate for a minimum 1/2 Venus solar day capture one day/night transition
	- Take / transmit measurements periodically timed for science need and to maximize transfer to orbiter / data relay

LLISSE

An Approach to achieve a class of long-lived landers for Venus

Artist's conceptions of the LLISSE platform and its various embodiments: a) Early concept for a battery-powered LLISSE after deployment; b) Windpowered LLISSE after deployment; c) SAEVe lander; d) V-BOSS lander; e) Notional comparison of the V-BOSS lander to a Venera lander; f) A version of LLISSE mounted on a traditional, larger lander.

LLISSE Intelligent Systems Introduction

- **LLISSE is a Complete, Compact, Stand-alone System Intended For Extended Operation On The Venus Surface**
- Intelligent Systems in the LLISSE Project Develops Three Core High Technologies for LLISSE Operation
	- \triangleright Electronics for sensor control and monitoring, signal conditioning, data processing, and power management without use of an environmentally controlled enclosure.
	- \triangleright Sensor systems for acquiring temporal meteorological and key atmospheric species data, momentum exchange between surface and atmosphere, and the rate of solar energy deposition.
	- Communications for data transfer from the Venus surface to an orbiter including circuit and antenna design. Determination of lander orientation.

Version of LLISSE in development ~10 kg and ~60 days life

National Aeronautics and Space Administration

HOTTech Project Technology Areas

HOTTech-2 Projects

HOTTech – High Operating Temperature Technology

https://www1.grc.nasa.gov/space/pesto/space-vehicle-technologies-current/high-operating-temperature-technology-hottech/

National Aeronautics and Space Administration

Electronics

High Temperature Electronics Advancements

R&D 100 Award 2018

- *Unique capabilities have produced the World's First Microcircuits at moderate complexity (Medium Level Integration) that have the potential for long-lived operation at 500˚C*
- **Circuits contain 10's to ~1000 of Junction Field Effect Transistors (JFETs); An order of magnitude beyond a few JFETs previously demonstrated**
- **Enables a wide range of sensing and control applications** *at High Temperatures*
	- **In-package signal conditioning for smart sensors**
	- **Signal amplification and local processing**
	- **Wireless transmission of data**
- **A tool-box of signal conditioning, processing, and communications circuits are being developed and demonstrated**

Cross-sectional illustrations of NASA Glenn 4H-SiC JFET-R devices with two levels of interconnect. (a) Simplified device structure drawing. (b) Scanning electron micrograph of Generation 10 JFET source and gate region

www.nasa.gov

NASA GRC Electronics Development

2017 NASA Glenn SiC JFET IC "Version 10" 1+ year of operation in Earth air oven at 500 ° C Achieved Version 10 ICs continue to **set high temperature durability world records in T ≥ 500 °C Earth-atmosphere oven testing.**

Complex ICs Operating more that 1 Year at 500 $^{\circ}C^{[1]}$

ICs Operating at World Record 961 °C[2]

^{[1] 2018} Int. Conf. High Temperature Electronics p. 71 [2] IEEE Electron Device Letters vo. 38 p. 1082 (2017).

60-Day Venus Environment IC Test (in GEER)1,2

Two IC Version 10 ÷2/÷4 Clock ICs (175 JFETs/chip) successfully operated in GEER Venus surface conditions for 60 days duration.

1Neudeck et al., IEEE J. Electron Devices Soc., vol. 1, p. 100 (2018). 2Chen et al., Proc. 2018 Int. High Temperature Electronics Conf.

NASA Glenn SiC JFET IC Technology Progress

"Learn by doing" fabricating and testing **successive upscaled generations** of prototype IC wafers/chips.

"IC Gen. 10" (2017)

(16-bit RAM, 195 SiC JFETs) 2 prototype 75 mm diameter SiC epi-wafers 6 µm gate length, 6 µm resistor width 3 mm x 3 mm, 32 I/O Bond Pads

Key IC Version 10 Accomplishments*

- **400+ days stable 500 °C electrical operation**
- **60 days stable Venus surface environment electrical operation**
- 961 °C electrical operation (shortterm)
- -190 °C cryogenic electrical operation
- Radiation immunity through 7 Mrad(Si) ionizing dose and 86 MeVcm2/mg heavy ions (25 °C)

"IC Gen. 11" (2018)

(120-bit RAM, ~ 1000 SiC JFETs) 6 µm gate length, 3 µm resistor width 4.65 mm x 4.65 mm, 32 I/O Bond Pads

Key IC Version 11 Accomplishments

- **5-fold reduction in logic gate power**
- **First ICs designed for LLISSE**
- 500 °C 8-bit Analog to Digital converter
- Few days $500 °C \sim 1$ kbit ROM operation

"IC Gen. 12" (2022)

4 prototype 75 mm diameter SiC epi-wafers 6 prototype 100 mm diameter SiC epi-wafers (248-bit RAM, ~ 2000 SiC JFETs) 3 µm gate length, 2 µm resistor width 5 mm x 5 mm, 62 I/O Bond Pads

Wafer fabrication in progress

*Published results, see https://www1.grc.nasa.gov/research-and-engineering/silicon-carbide-electronics-and-sensors/technical- _{WWW.nasa.gov} publications/

Example Sensors/Instruments

LLISSE Sensors Summary

Broad Array Of Sensor Technology For Venus Applications Leveraged From Aeronautics Development

- Long History Of Active Development of Harsh Environment Smart Sensors Systems For Engine Test Stand, Health Management, and Intelligent Engines
- Multiple Demonstrations/Applications e.g., Including On-wing Engine **Testing**

Development Approach

- Miniaturized Sensor Systems Produced By Microfabrication Techniques and High Temperature Compatible Materials
- Parallel Development Of Multiple Sensor Types
	- Multiple Chemical Species
	- \triangleright Temperature
	- Wind (3 Directions)
	- **>** Pressure
	- \triangleright Radiance
- Each Sensor Has Targeted Specifications and Associated Electronics **Requirements**

Status

- Several Sensors Have Reached High Levels of Maturity For This Application
- Integration of Multiple Sensor Types with SiC Electronics Demonstrated

Courtesy of D. Makel, Makel Engineering, Inc.

SiC Electronics Combined With Chemical Sensor for GEER Testing

High Temperature Pressure Sensor

LLISSE Chemical Sensors Status Chemical Sensors Summary

Background: *Sensor Array Developed Under Completed NASA Phase I and Phase II SBIR*

- \triangleright Demonstrated Measurement of Key Species Including SO₂, H₂O, OCS, CO, HCl, and HF Under Relevant Conditions
- \triangleright Sensors are selective to targeted species with minimal cross sensitivity to other species in Venus atmosphere

Status: *Development of Chemical Sensors (including GRC sensors)*

Integrated with NASA GRC SiC Electronics On-Going in HOTTech project

Four Chemical Microsensors $(SO₂, CO, OCS, HF)$ Tested for 60 days in Venus Simulated Conditions in GEER

- All 4 Sensors Operated Nominally During 60 Day Test
- First Demonstration of In-Situ $SO₂$ Tracking in GEER for Extended Periods
- HF Sensor Integrated With Signal Transduction/Amplification SiC Electronics Monitored HF Boosts in GEER 10 Day Test

TRL Summary: Four chemical sensors successfully tested in Venus conditions for 60 days with SO2 sensor tracking concentration changes and consistent with gas chromatograph readings. HF sensor with SiC electronics responded to concentration changes in 12 day testing.

SO₂ Sensor Operation in GEER for **60 Days in Venus Simulated Conditions**

SO₂ MicroSensor

Venus In Situ Surface Imager (VISSI)

PI: Jeffrey Balcerski, Ohio Aerospace Institute

Target Application: Venus surface – long duration

Science:

- Obtain high resolution digital images of the surface of Venus at multiple scales
- Resolve geologic features near landing site at a resolution of 1 mm/px at 1 m
- Observe transient phenomena (i.e. active sediment transport) over the period of days to weeks
- Resolve basic rock and mineral types via optical filters

Objectives:

- Develop imaging array of high-temperature photodiodes sensitive to visible spectrum
- Develop high-temperature electronics to produce transmit-ready digital image data
- Identify and integrate appropriate optical lenses and filters
- Test and demonstrate the operation of all components at Venus surface conditions for extended time (days to weeks)

CoIs: Gary Hunter, Geoffrey Landis, Phillip Abel – NASA Glenn Research Center; Martha Gilmore – Wesleyan University

Figure Caption: A new generation imager for the surface of Venus.

Planned Key Milestones (Tentative Based on Facility Availability/Pre COVID):

- 4Q FY19: Performance requirements for VISSI
- 3Q FY20: Demonstrate Photodiode and Amplification at 500ºC
- 3QFY20: Demonstrate Photodiode for 60 days at 500ºC
- 2Q FY21: First generation VISSI electronics evaluated at 500ºC
- 4Q FY21: Integrated photodiode array and electronics providing image at 500ºC
- 3QFY22: Image produced at 500ºC
- 4Q FY22: VISSI proof-of-concept demonstration in Venus simulated conditions

TRL 3 to 4

High-Temperature MEMS based seismometer

HOTTech – High Operating Temperature Technology

Team Member(s)/Institution(s)

Technology Overview/Description

Overall objective:

Leverage existing MEMS seismic sensor, recent developments in high-temperature electronics and sensors, terrestrial analogues and Venus seismicity studies, and an expert team to design and mature a MEMS based seismometer suitable for use on long-duration Venus landers, like SAEVe.

Accomplishing this involves:

- Assessing / modifying existing MEMS seismic sensors that may be suitable for Venus applications
- Developing driving/interfacing electronics to support required operations and interfaces of a notional lander
- Design and fabricate a 1-axis instrument (but readily scalable to 3 axis) and verify performance via tests and analysis. Iterate.
- -Mature instrument and demonstrate performance of breadboard system in Venus surface conditions against model-based predictions and reach a TRL of 4 or greater

Technology Goals

- 1. Develop science-based requirements for a Venus seismometer that consider the Venus unique operations circumstances
- 2. Assess MEMS seismic sensors, modify as required, and fabricate and test under Venus conditions
- 3. Analysis and the sensor / electronics system and design, fabricate and test a 1 axis system that meets requirements and is consistent with expected Venus mission applications
- 4. Demonstrate operations of breadboard 1 axis instrument in Venus conditions

Starting TRL: 2 Ending TRL: 4

Communications

LLISSE Communications Summary

History of Cutting Edge Development in High Temperature Wireless Communications

- Wireless Signal Spectra For High Temperature Seismometer Sensor Displacements Demonstrated (2012)
- Demonstrated Wireless Pressure Sensor At 475°C Including Pressure Sensor, SiC Circuitry, and Wireless Circuit (2013)

Development Approach

- Activities Include Venus Relevant Development Of Antennas, Transmitters, and Other Components
- Increasing Capabilities and Complexity of High Temperature Electronics Circuits Increases Communication System Capabilities
- Targeted Operation of Communication System from 100 to 150 MHz.

Status

- Development of Circuit Hardware Architecture for Higher Frequency Communications Systems On-going
- Baseline LLISSE Antenna Materials and Design Approach Identified And Initial Material Testing In Venus Simulated Conditions Begun
- Proof-of-concept Demonstration of Ability to Determine Orientation of the Lander from the Communication System Achieved
- Propagation studies conducted in GEER at higher frequencies; transmission with limited losses observed.

Wireless seismometer and circuit in an oven at 500ºC

Wireless Pressure Sensing Circuit

LLISSE Communications Status

Baseline Communications Approach

- Communications System Includes: Active Circuits, Passives, Antenna
- Targeted 100 MHz Frequency Range; Relevant for Venus Surface Operations
- Communication System Dependent on SiC Circuit Advancements

 First SiC-based Communication Circuit Designed To Operate On A Long-lived Venus Lander Based on SiC JFET technology Demonstrated

- Final Communications System at 100 MHz Will Be Based on BJT (Not JFET) **Transistors**
- Antenna Materials Must Be Both Resilient to Venus Surface Conditions and Have High Permittivity

National Aeronautics and Space Administration

Power

LLISSE Power

Performance Summary

Voltage (max./min.): +25 V/ 0.0/-25 V Current: 0.2 with pulses up to 12A Life: 60 Earth days Temperature: + 4650C Environment: Venus Surface @ 90 Bar

Configuration Volume: 1.07 liters Weight: 2.83 kg 2.39 Ampere-Hours 95.6 Watt-Hours @ 40 V 89 Watt-Hour/liter

SUMMARY AND FUTURE PROPECTS

- **Venus Surface Exploration Has Unique Technical Challenges Due To The Extreme Environment**
- **Venus Technology Plan: More complex missions are envisioned as a range of technologies mature**
- **The Combination of Smarts, Mobility, and Extended Life is Enabling for Surface Lander Platforms**
	- **Impact On Both Science Delivered and Mission Capabilities**
- **A Range Of Harsh Environment Technologies Are In Development To Enable Long Life Surface Missions in e.g., LLISSE and HOTTech**
	- **Electronics, Packaging, Communications, Power, Actuation**
	- **HOTTech 2016 Awarded 12 Awards**
	- **HOTTech 2021 Awarded 7 Awards**
- **Recent Advances Have Been Significant And The Prospect Of Longlived Missions On The Venus Surface Is Becoming Increasingly Viable**

Backup

- Gary Hunter, NASA Glenn (Chair)
- Jeffery Balcerski, Ohio Aerospace Institute/NASA Glenn
- Samuel Clegg, Los Alamos National Laboratory
- James Cutts, NASA JPL
- Candace Gray, New Mexico State University
- Noam Izenberg, Applied Physics Lab
- Natasha Johnson, NASA Goddard
- Tibor Kremic, NASA Glenn
- Larry Matthies, NASA JPL
- Joseph O'Rourke, Arizona State University
- Ethiraj Venkatapathy, NASA Ames

Technology Framework

